

Sandia Microsystems: Impact from Science to Industry

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Physical, Chemical and Nano Sciences Center
Sandia National Laboratories**

August 30, 2011

Sandia National Laboratories is a multi-program laboratory managed and operated by Sandia Corporation, a wholly owned subsidiary of Lockheed Martin Corporation, for the U.S. Department of Energy's National Nuclear Security Administration under contract DE-AC04-94AL85000.



A stylized graphic of the American flag, featuring a blue field with white stars and red and white wavy stripes, positioned behind the title text.

National labs take on big problems for the nation

Sandia's Missions

Nuclear Weapons	Defense Systems & Assessments	International, Homeland, & Nuclear Security	Energy, Climate, & Infrastructure Security
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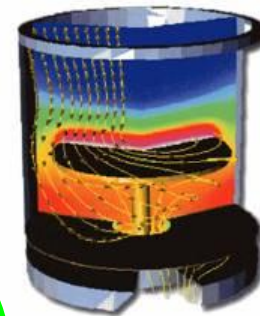
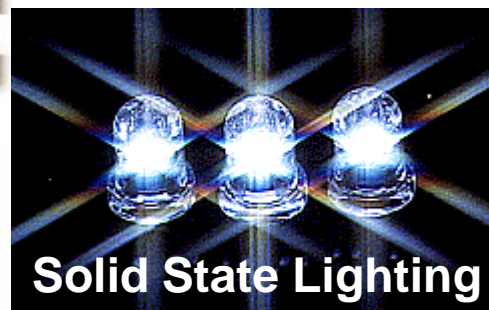
Energy, Climate, & Infrastructure Security

 Sandia National Laboratories

Bring impact through partnerships with industry



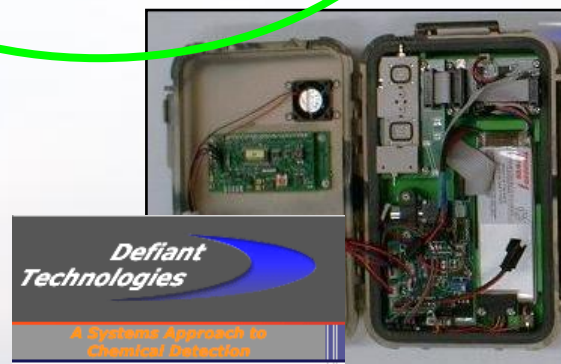
GOODYEAR



EMCOPA



PURE POWER :: MADE SIMPLE



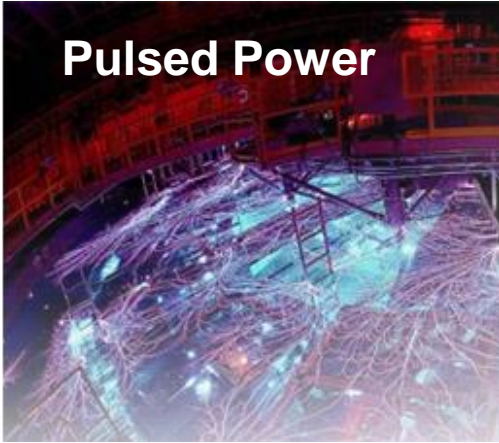
Industry brings products to market, not national labs
National labs shouldn't compete with industry or universities



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Sandia has multiple unique strengths that industry partners utilize

Pulsed Power



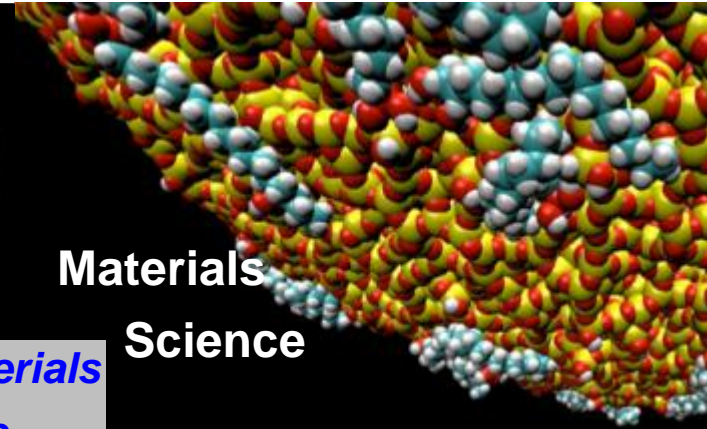
**Computer
Science**



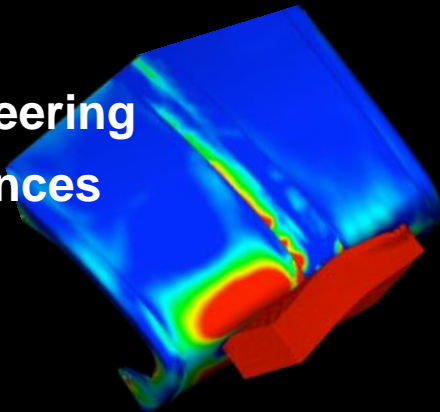
Semiconductor materials

Surface science

**Materials
Science**



**Engineering
Sciences**



Composite materials
Science of Defects
Electronics, Optics, &
Mechanics

**Nano &
Microelectronics**

JF055301A-09 30.0kV x60 200µm

Bioscience

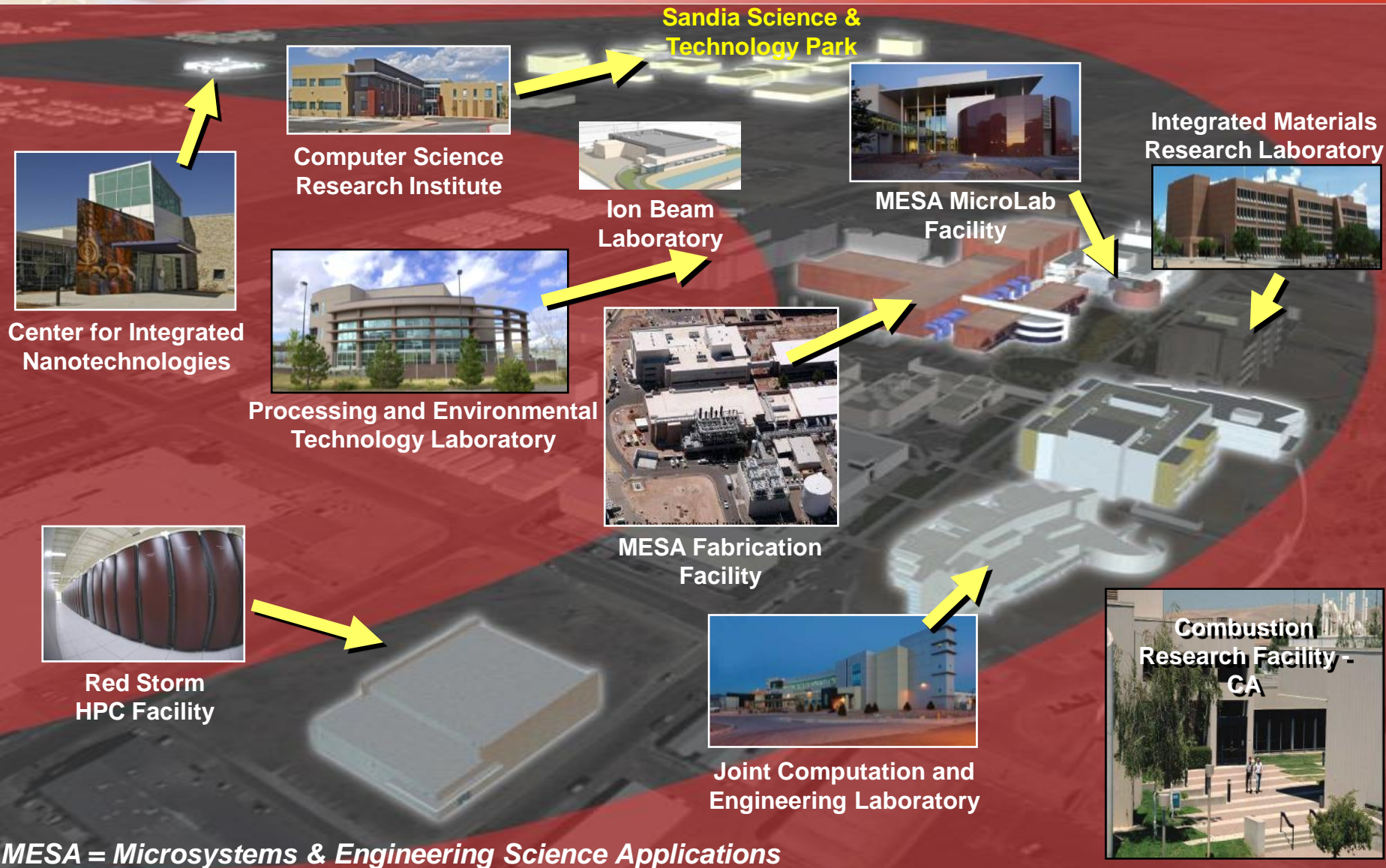


**Fundamental research and discovery in science and engineering
advance our missions**



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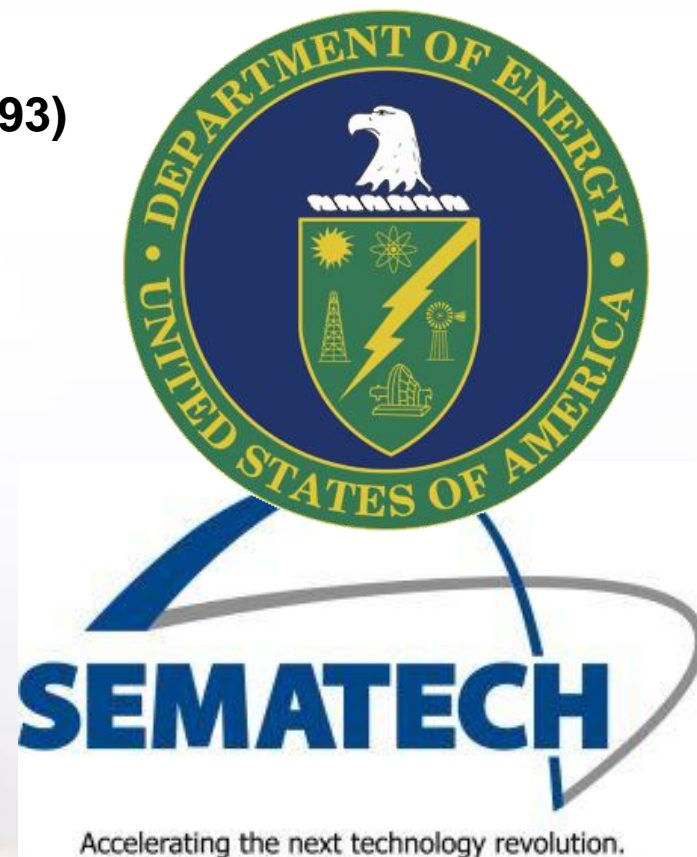
Unique Facilities in the NM Innovation Corridor & Livermore Valley Open Campus



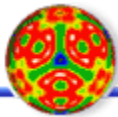
SEMATECH CRADA

SEMATECH and DOE sign a 5 year CRADA (1993)

- materials and process analysis
- equipment modeling and design
- semiconductor process analysis
- equipment benchmarking and engineering
- contamination free manufacturing research
- equipment and software reliability

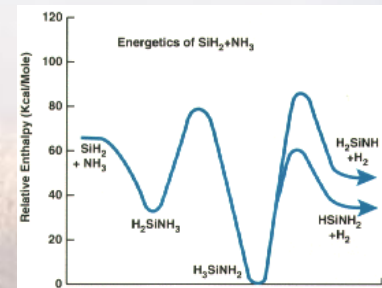
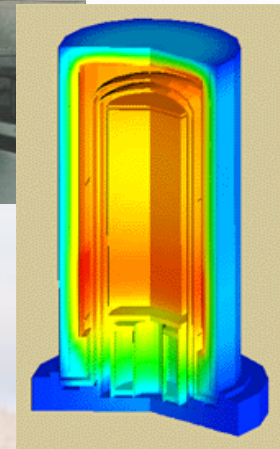
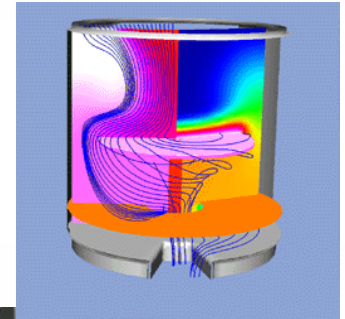


Government Investment in Basic R&D



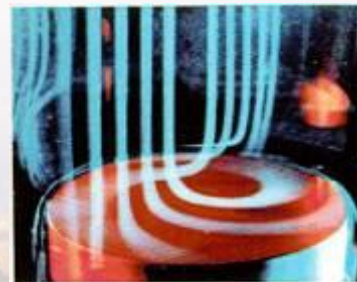
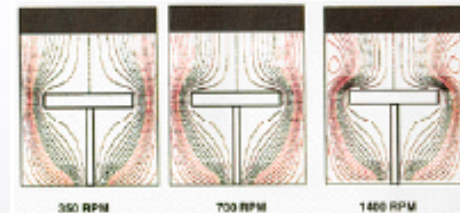
Office of Basic Energy Sciences

- Sandia expertise in metal-organic chemical vapor deposition technology
- Basic R&D in:
 - Fundamental materials physics
 - Growth chemistry and reactor physics
 - In-situ monitoring and stress-engineering



First CRADA with EMCORE

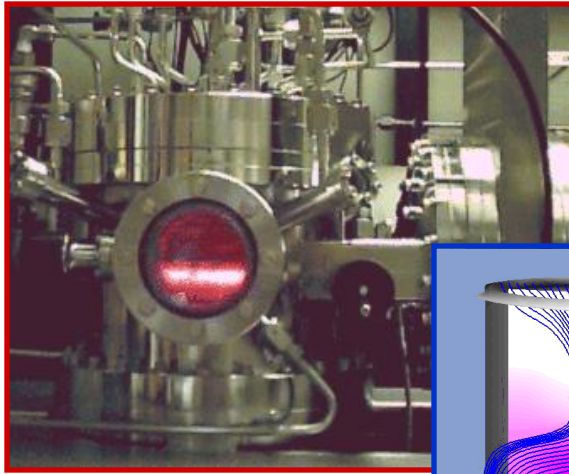
- EMCORE signs \$3.9M CRADA with Sandia (1993).
- Apply Sandia expertise for design of production-scale rotating-disk MOCVD reactor
- CRADA spans six years.



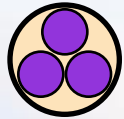
Sandia Helped Emcore Design Next-Generation MOCVD Reactor: ENTERPRISE 400

“A sterling example of the benefits of such partnerships. In business, time is money, and Sandia’s responsiveness has helped us greatly in our market.”

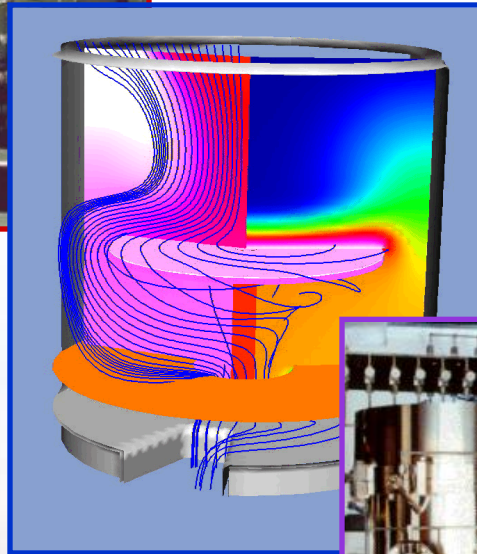
Norm Schumacher, Pres., Emcore, ca. 2001



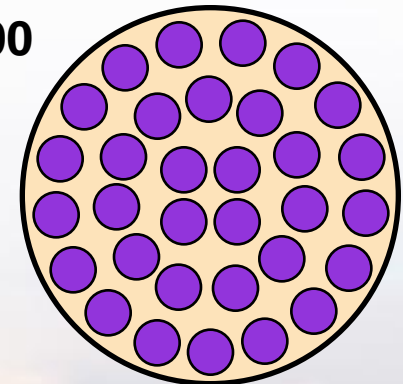
Emcore
Discovery 125



3 two-inch wafers
(Earlier reactor)



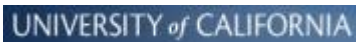
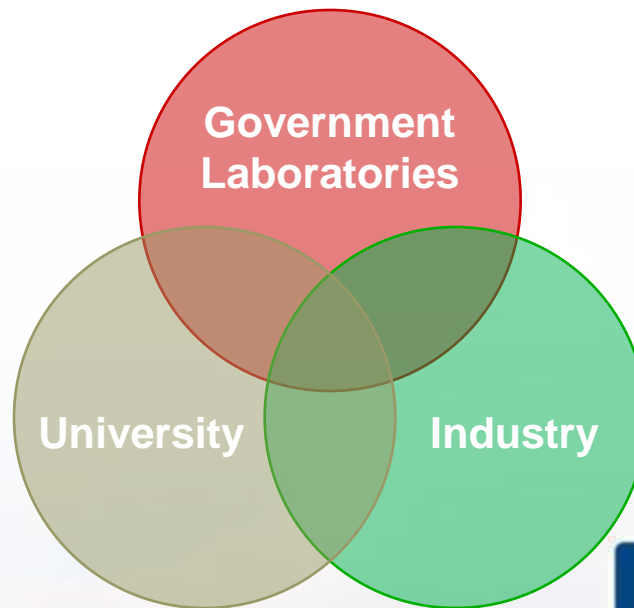
Emcore Enterprise 400



32 two-inch wafers
(New reactor design)

Big problems take multiple partners

Accelerating Innovation



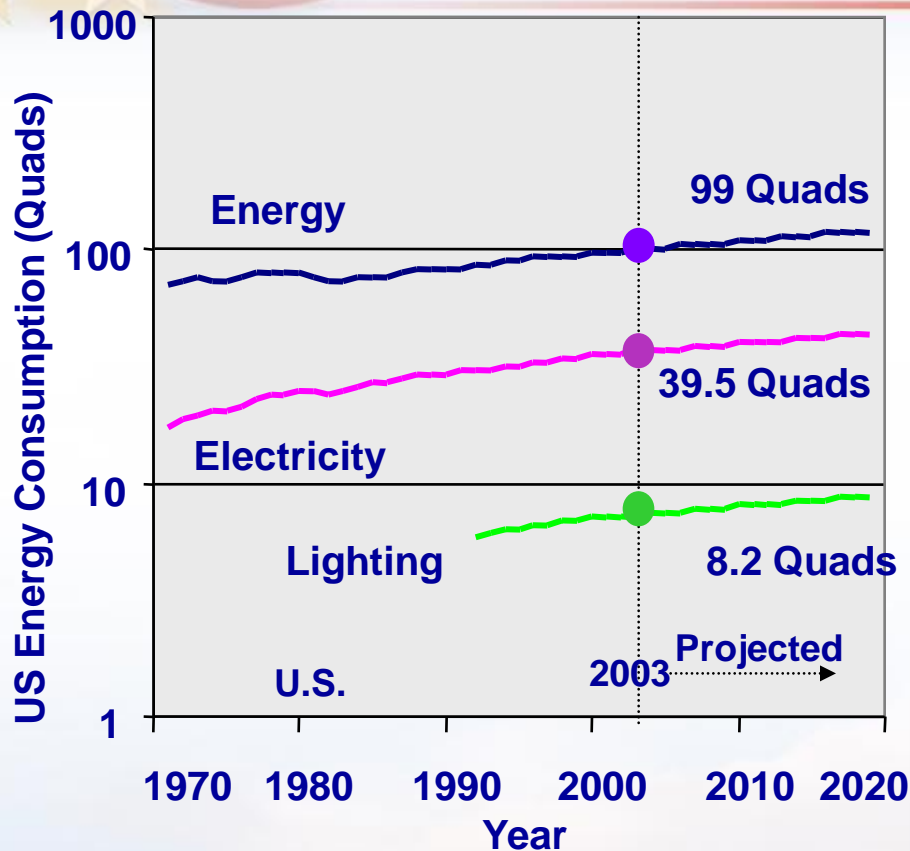
Taking on the world's toughest energy challenges.



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Energy security is a big problem



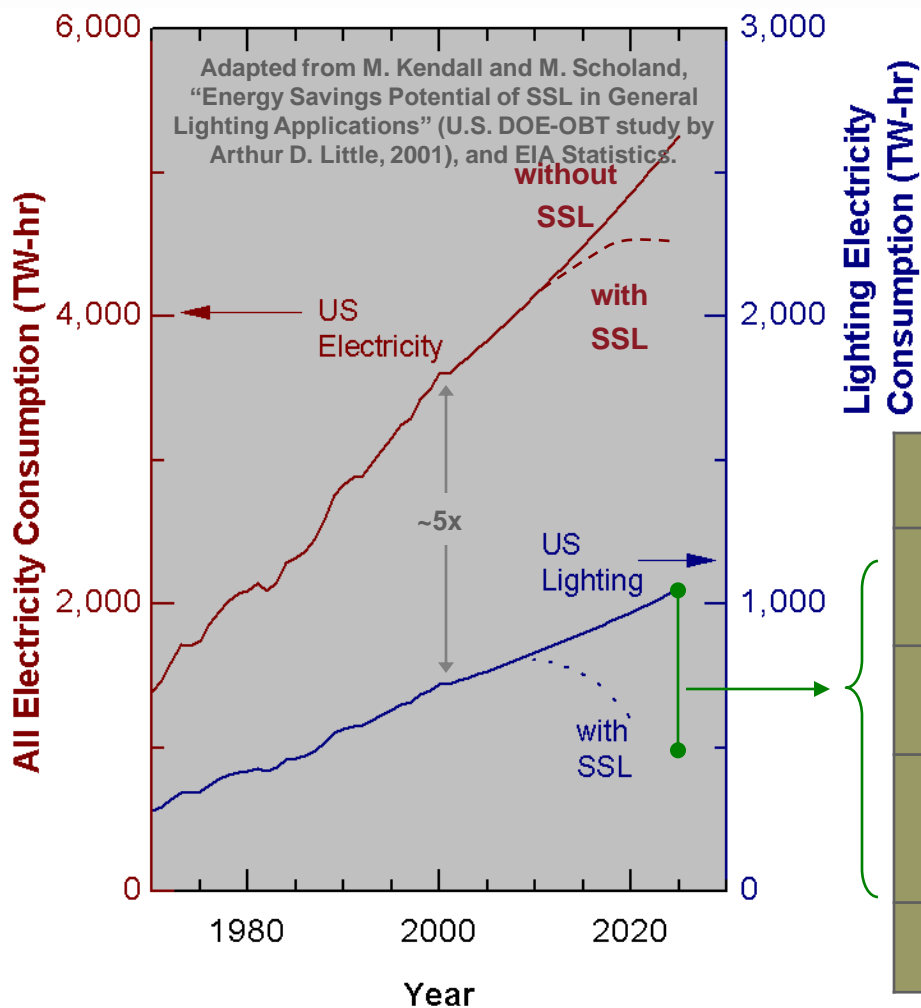
- ~22% of electricity consumption is for general illumination
- Lighting is a highly attractive target for reducing energy consumption!

Efficiencies of energy technologies in buildings:

Heating:	70 - 80%
Elect. motors:	85 - 95%
Fluorescent:	20-25%
Incandescent:	~5%



50% efficient SSL delivers a huge energy saving



■ SSL has the potential, by 2025, to:

- decrease electricity consumed by lighting by >50%
- decrease total electricity consumption by >10%

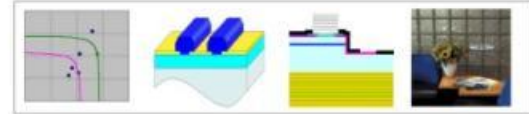
<u>Projected Year 2025 Savings</u>	<u>US</u>	<u>World</u>
Electricity use at site (billion kWh)	525/year	1,800/year
Money spent on Electricity	\$35B/year	\$120B/year
Electricity generating capacity (GW)	75	~260
Carbon emissions (Mtons)	75	~260

Significant Industrial Collaborations Began in 2000 and Continue Today

- Philips Lumileds (originally with HP)
 - General Electric
- Cabot Superior Micropowders
 - Dow Corning
 - Veeco
 - Emcore
 - Cree

Light Emitting Diodes (LEDs) for General Illumination

FULL EDITION



AN OIDA TECHNOLOGY ROADMAP UPDATE 2002

Revision Date: 29 August 2002
Sponsored by: Optoelectronics Industry Development Association (OIDA)
National Electrical Manufacturers Association (NEMA)
Department of Energy - Office of Building Technology, State and Community Programs
Edited by: Jeff Y. Tsao, Sandia National Laboratories
Published by: **OIDA** OPTOELECTRONICS INDUSTRY DEVELOPMENT ASSOCIATION

2002 OIDA LED Technology Roadmap (edited by SNL)

Sandia hosted & edited DOE/OIDA SSL Technology Roadmap Workshops in 2000 and 2002, and provided technical background information to congress



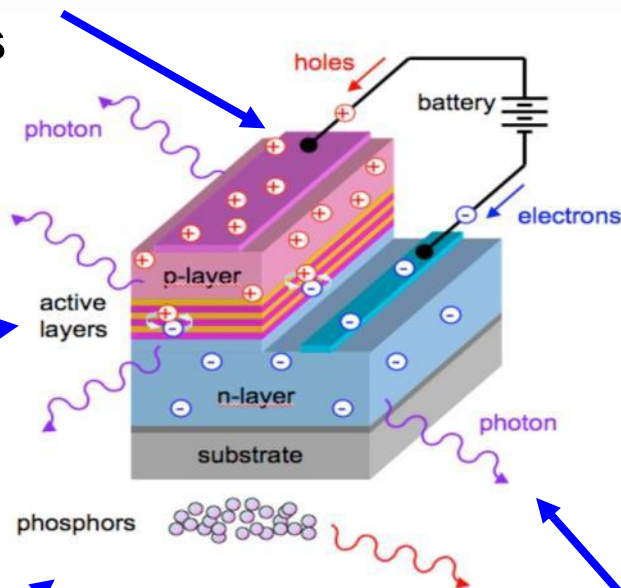
Science and technology challenges

**Injection & transport
of charge carriers**

**Radiative & non-radiative
recombination**

**Color conversion &
multi-color mixing**

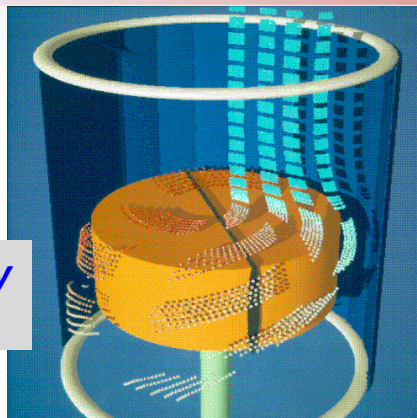
Light extraction



Initial solutions to science and technology challenges: material deposition

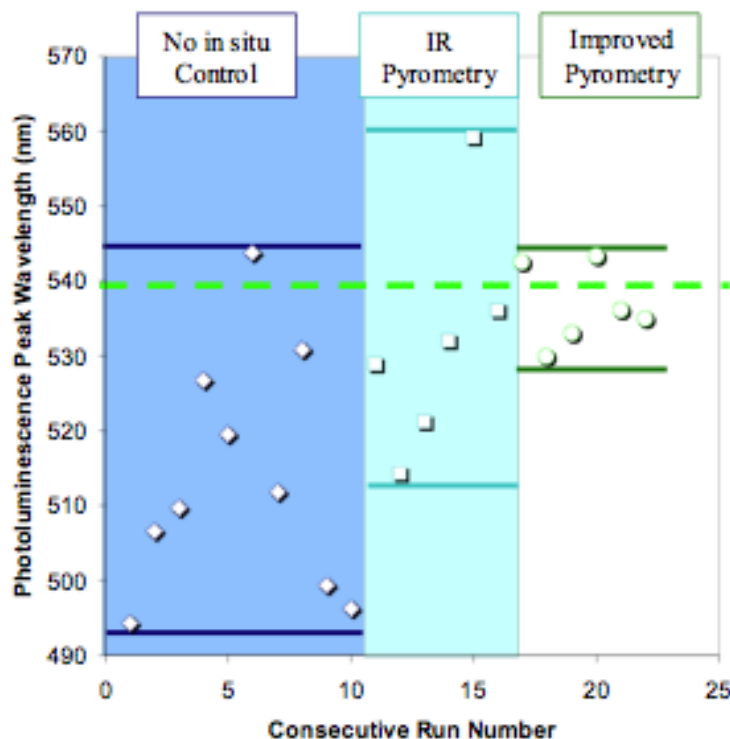
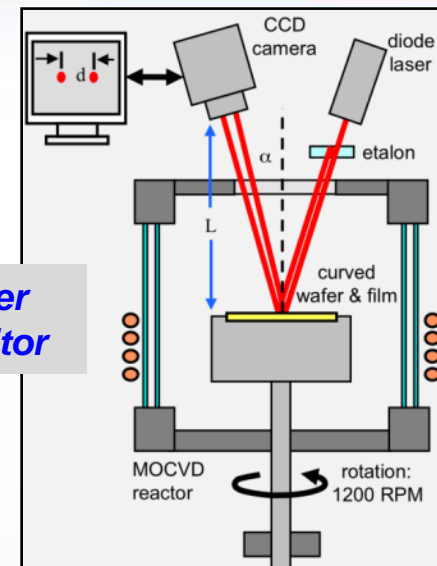
Chemical Vapor Deposition Sciences

Modeling of chemically reacting flows



Advanced Growth & Science of Epitaxy

In-situ wafer stress monitor

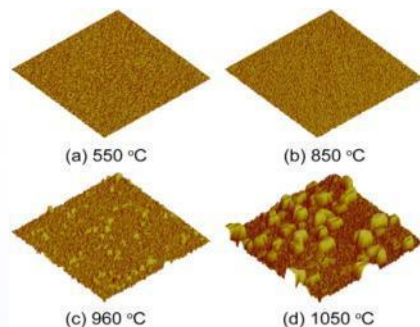


Target:
540 nm

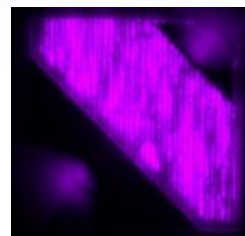
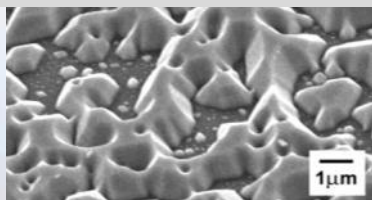
Emissivity-correcting pyrometer increases MOCVD temperature control, dramatically reducing run-to-run wavelength variations

Developed chemical & mechanistic understanding, theory, and new synthesis methods

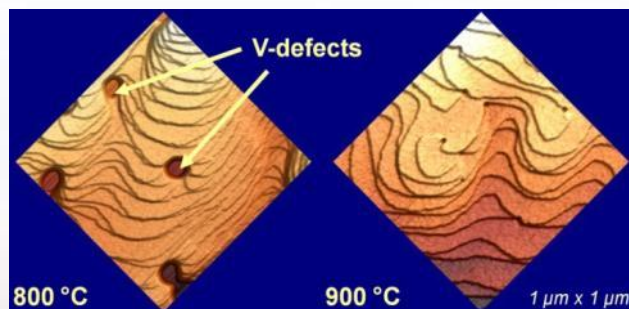
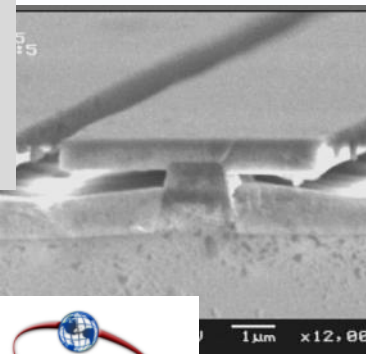
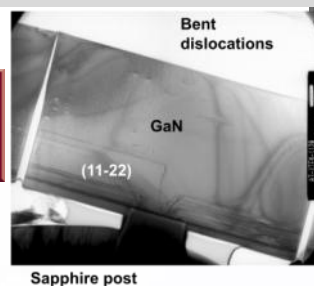
Understanding and Control of Material Defects



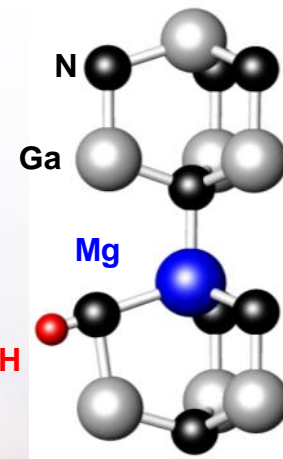
Controlled GaN growth nucleation reduces defect densities and strain relaxation



Cantilever Epitaxy reduces dislocation densities 100X (R&D 100 Award)



Extended and point defect dependence on growth temperature



DFT calculations of defect energies

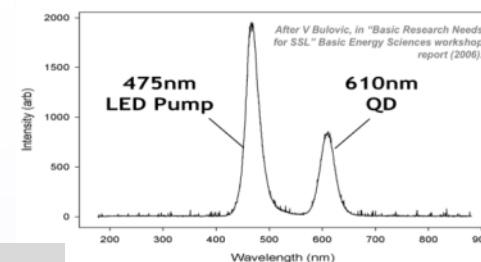
Science and technology challenges: color conversion

Need new phosphors:

- Fluorescent lighting phosphors are *unsuitable* for SSL
- Efficiency improvements, *especially red*
- Fast photoluminescence lifetimes
- High-T operation
- Low cost
- Non-toxic
- Compatibility with encapsulants
- Long lived under high UV flux

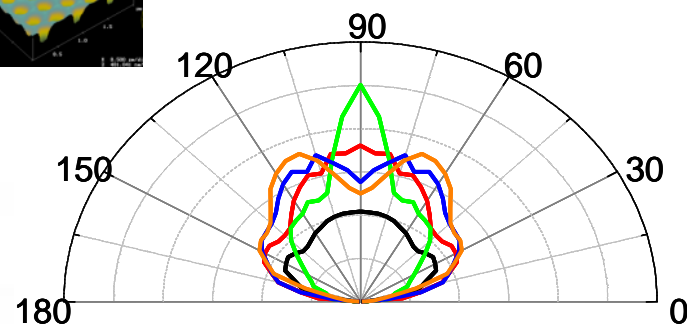
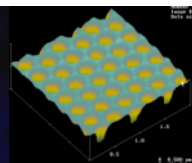
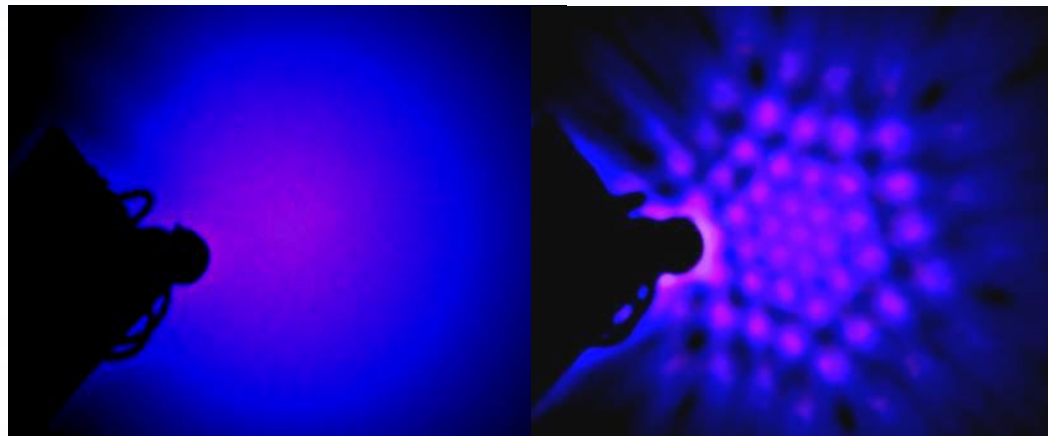
*Quantum dots as an engineered
alternative to conventional
phosphor materials*

Luminescence of CdS QDs



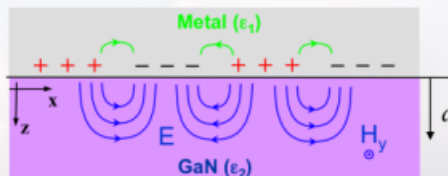
Improving extraction efficiency and light directionality

Lumileds, Sandia, and UNM (Wierer et. Al., APL 84, 3885 (2004))

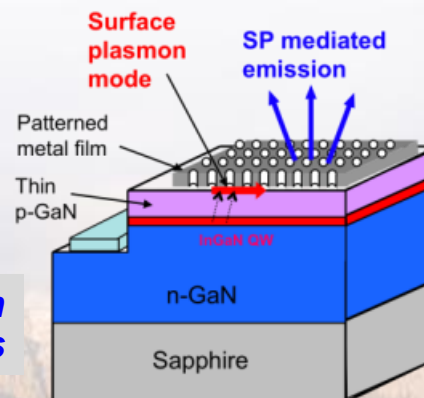


Photonic crystal LEDs exhibit directionality and 50% higher external quantum efficiency

New concepts



Surface plasmon mediated emission from InGaN LEDs using patterned metal films



LEDs Are Already Superior for Monochromatic Applications

MGM Grand's Teatro



**Providence Performing
Arts Center**



**Programmable Lights Ben
Franklin Bridge, Philadelphia
(Color Kinetics)**

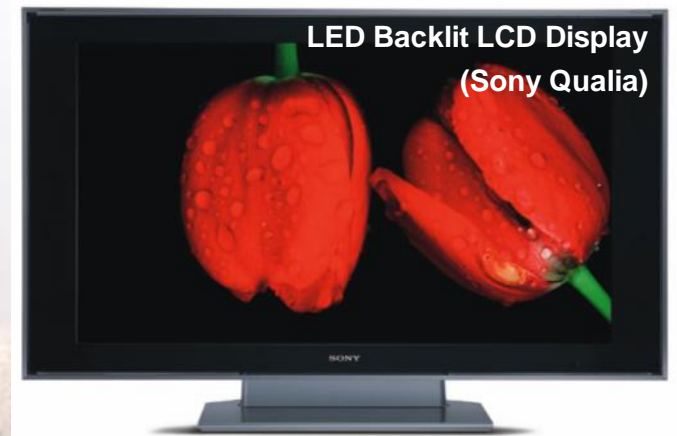


**LED Flash
Camera Phone
(Motorola E815)**

**Rear Combination Lamp
(LumiLeds)**



**LED Backlit LCD Display
(Sony Qualia)**



Replacing conventional lighting for general illumination is a greater challenge



**Cree LRP-38 Replacement
Lamp**



**Philips 60W Incandescent
Replacement**

**Although there is initial commercialization,
important science questions remain and so
the partnerships evolve and mature**

Solid state lighting science is a new DOE energy frontier research center (EFRC)



Research:

- Investigate conversion of electricity to light using radically new designs: nanowires, QDs, hybrid architectures, sub-wavelength structures
- Understand and eliminate defects in SSL semiconductor materials that presently limit the energy efficiency

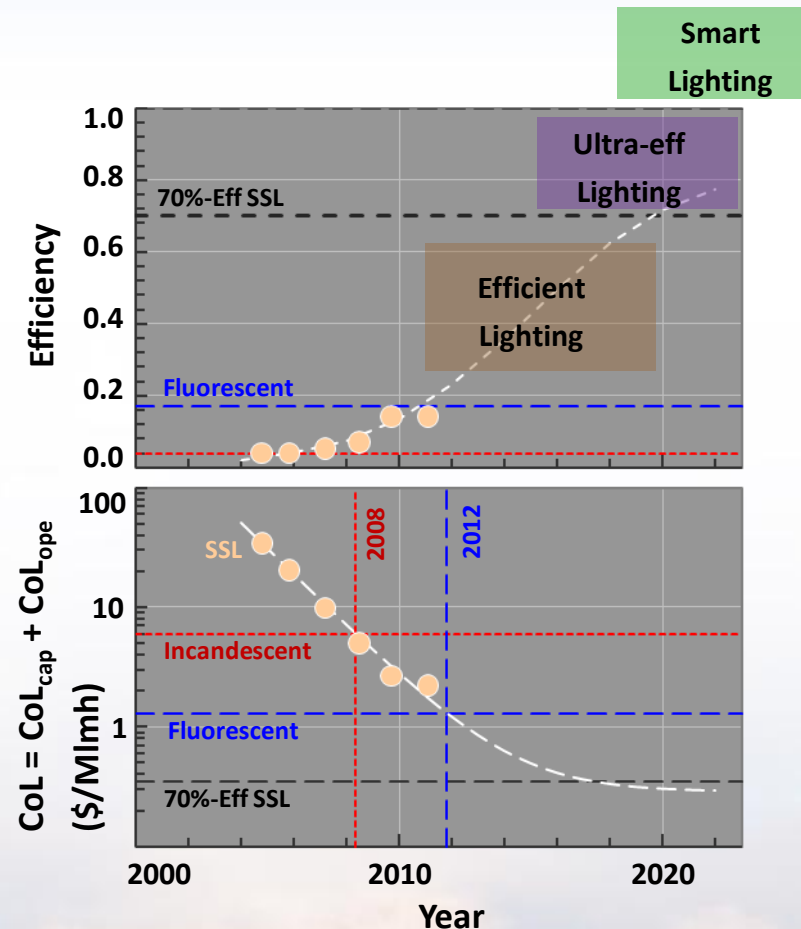


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Challenges for next-generation solid state lighting

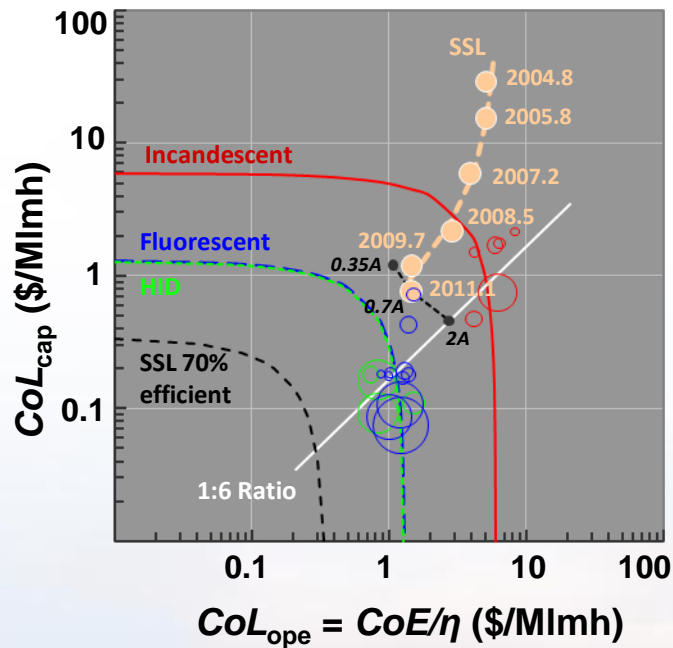
SSL technology

- Will soon “beat” traditional lighting
- Opportunity for higher risk challenges that take SSL well beyond traditional lighting:
 - >70% light production efficiency (ultra-efficient lighting)
 - >??% light use efficiencies (smart lighting)

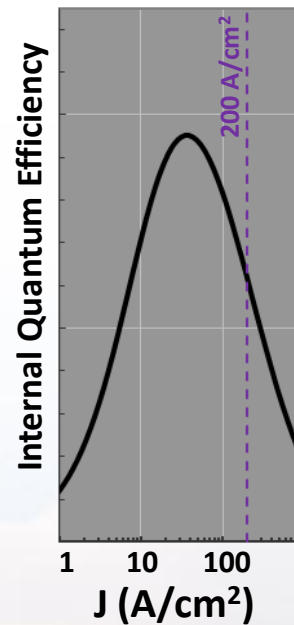


Fundamental experiments and theory to understand efficiency droop

High injected current densities are one route to lower capital cost of light,



if not for efficiency droop,



a phenomenon that we don't yet understand

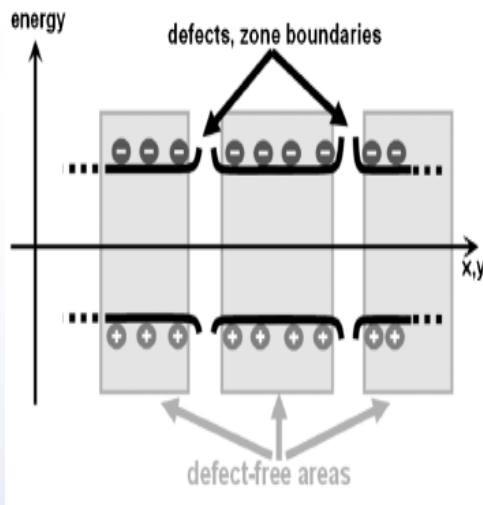
$$\varepsilon = \left(\frac{V_{ph}}{V_{ph} + IR} \right) \cdot \varepsilon_{inj} \cdot \frac{BN^2}{AN + BN^2 + CN^3 + \dots} \cdot \varepsilon_{ext}$$

Annotations for the equation:

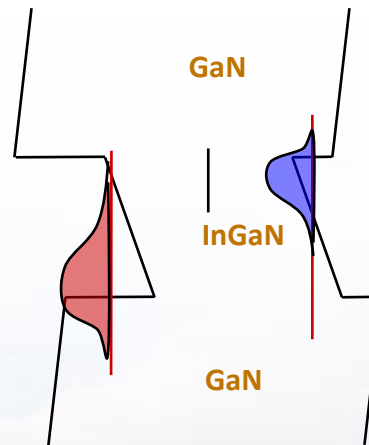
- $2.8V$ points to V_{ph}
- 0.6Ω points to IR
- ε_{Joule} (Joule efficiency (resistive losses)) points to the IR term in the denominator of the first fraction.
- ε_{inj} (Injection efficiency (carrier overshoot and escape)) points to the ε_{inj} term.
- AN points to the first term in the denominator of the second fraction.
- BN^2 points to the second term in the denominator of the second fraction.
- CN^3 points to the third term in the denominator of the second fraction.
- ε_{IQE} (Internal quantum efficiency) points to the entire second fraction.
- ε_{ext} (Extraction efficiency (photon trapping and absorption)) points to the ε_{ext} term.
- Additional labels for the second fraction: Spontaneous Emission (pointing to BN^2), Shockley-Read-Hall (defect-mediated) (pointing to AN), and Auger-like (pointing to CN^3).

Key Challenges: Treating Inhomogeneous Distributions

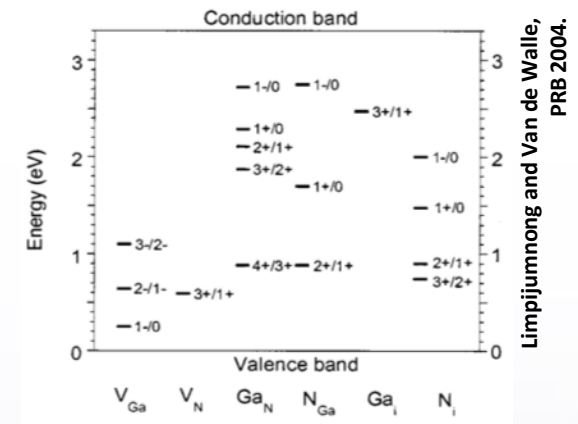
Distribution of bandgaps and defects in xy-plane



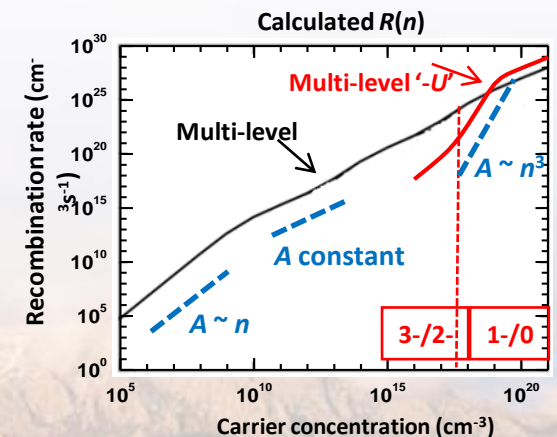
Distribution of polarization fields and carriers along z-axis



Distribution of deep-levels over charge states

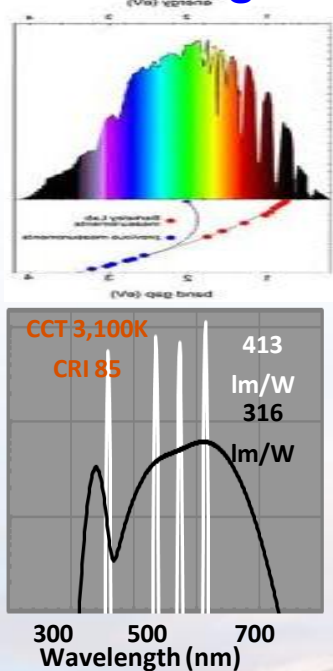


Limpijumnong and Van de Walle, PRB 2004.

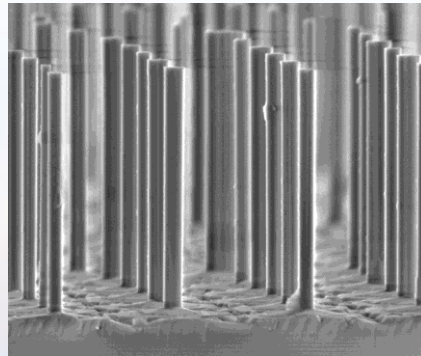


Beyond 2D: 1D Nanowire Synthesis, Properties, Architectures

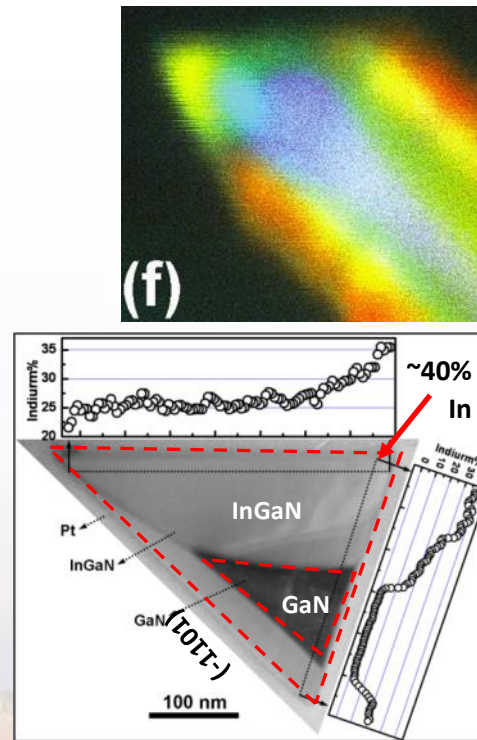
High InGaN compositions needed to span the desired SSL wavelengths



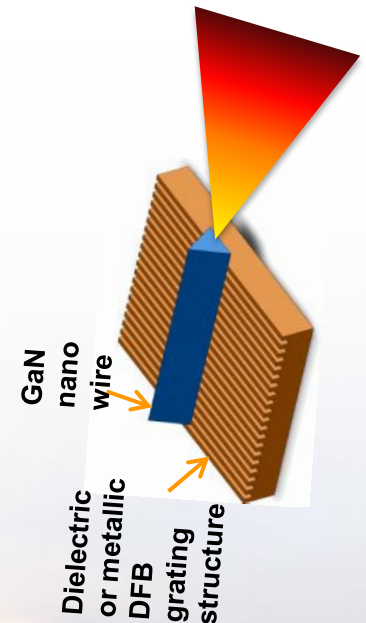
High aspect ratio enables strain accommodation



Measurements verify 40% InGaN, with anisotropies

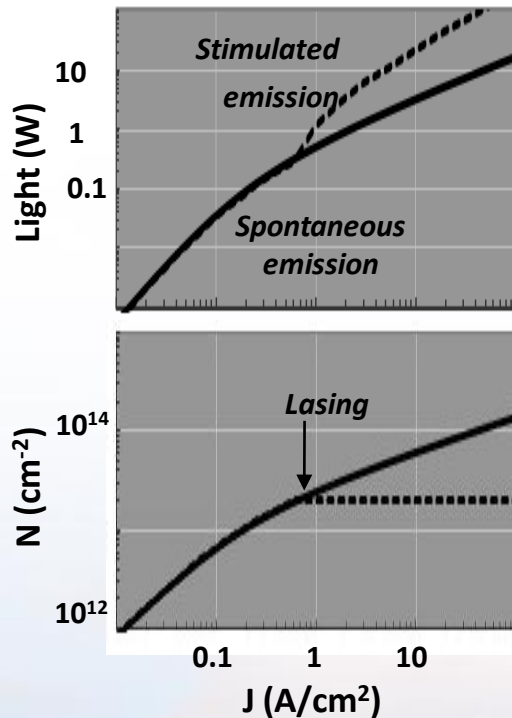


Future work: InGaN nanowire lasing!

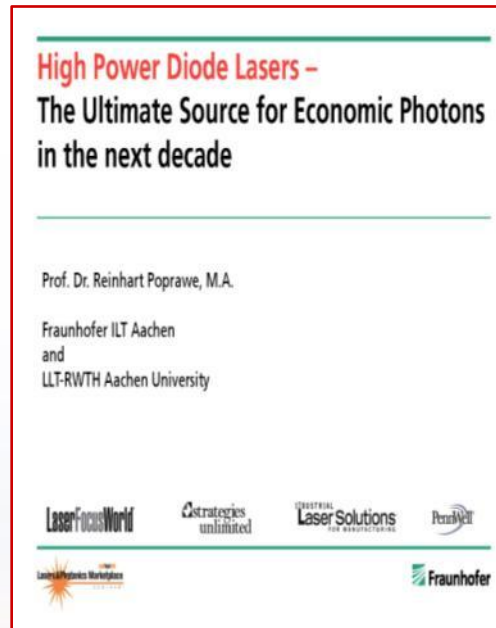


Novel emitter architectures capable of $>70\%$ efficiency at $>200\text{A}/\text{cm}^2$ (e.g., lasers)

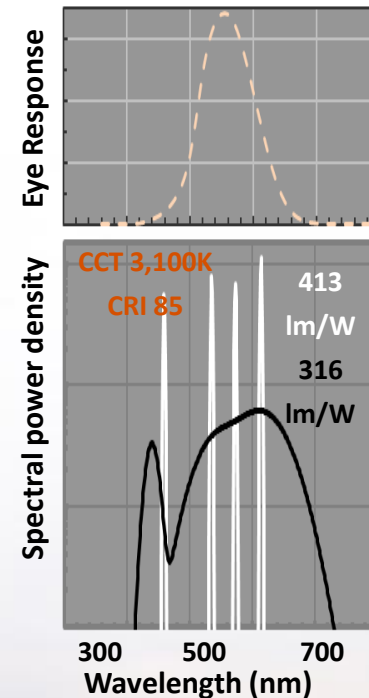
Stimulated emission
clamps carrier densities



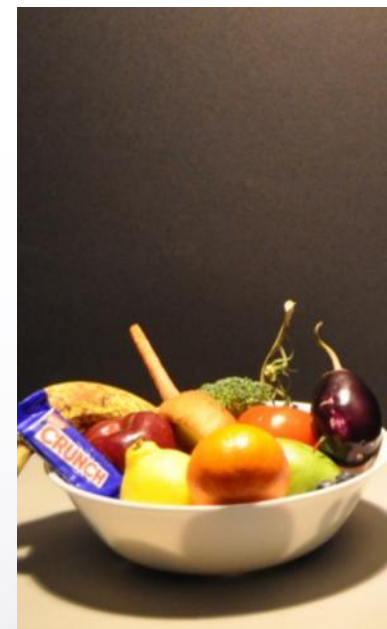
High current density
enables cheap photons



Narrow linewidths
give high LER



without sacrificing
color quality



Bringing luminaire functionality to the chip



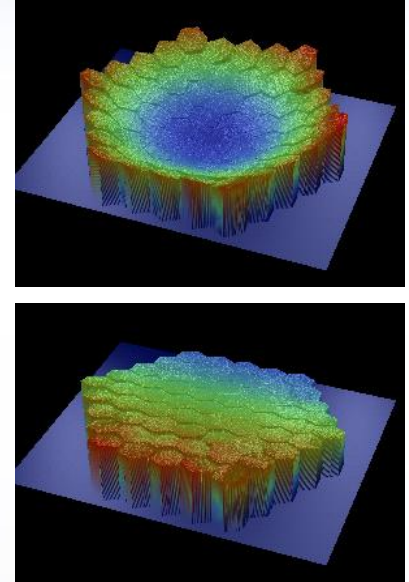
Theatre luminaire (expensive)

- Rotates, tilts, focuses, changes chromaticity, digitally controlled
- Hemispherical array gives the ultimate control over the illumination of a scene, but can only afford a few

Microsystem luminaire (inexpensive)

- Same functionality as theatre luminaire, but fractionated and ubiquitous
- Opportunity for much higher efficiency and productivity of light use

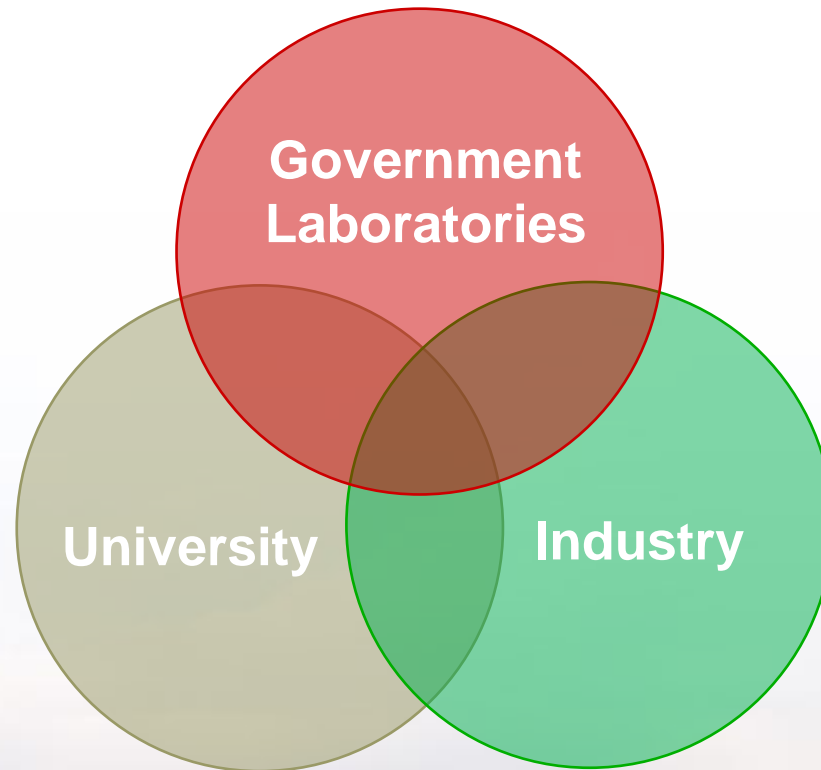
Piston-tip-tilt mirror array (courtesy of Olga Spahn, Sandia Labs)



Challenges

- Luminaire itself
- Integration of luminaire with light sources
- Heat sinking
- Color mixing

Investments in microsystems partnerships will create the next revolution in lighting and reduce energy consumption



Thanks to: Jerry Simmons, Jeff Tsao, Bob Biefeld, Mike Coltrin, Mary Crawford, Jon Wierer, Randy Creighton, Dan Koleske, Bill Breiland, David Follstaedt, George Wang, Art Fischer, Alan Wright, Normand Modine, Steve Brueck, Andy Armstrong, Fred Schubert



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